N-Channel Silicon MOSFET



**CPH3408** 

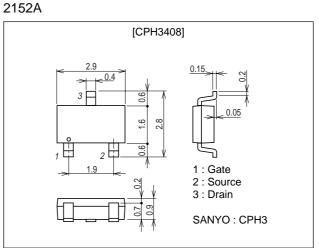
# **Ultrahigh-Speed Switching Applications**

### Features

- Low ON-state resistance.
- Ultrahigh-speed switching.
- 4V drive.

## **Package Dimensions**

unit : mm



## Specifications

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		5	Α
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	20	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm)	1.2	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	30			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =30V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.0		2.4	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =3A	4.5	6.5		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	ID=3A, VGS=10V		33	43	mΩ
	RDS(on)2	ID=1A, VGS=4V		48	68	mΩ

Marking : KH

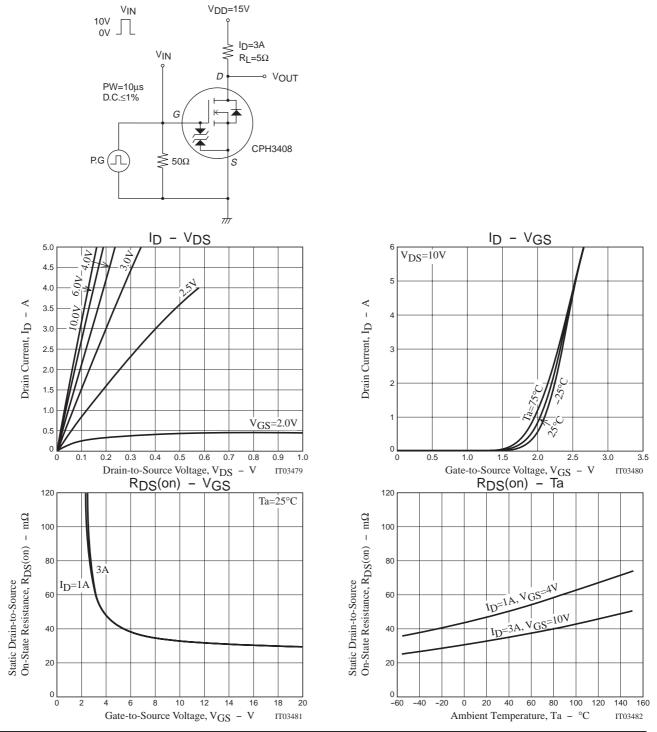
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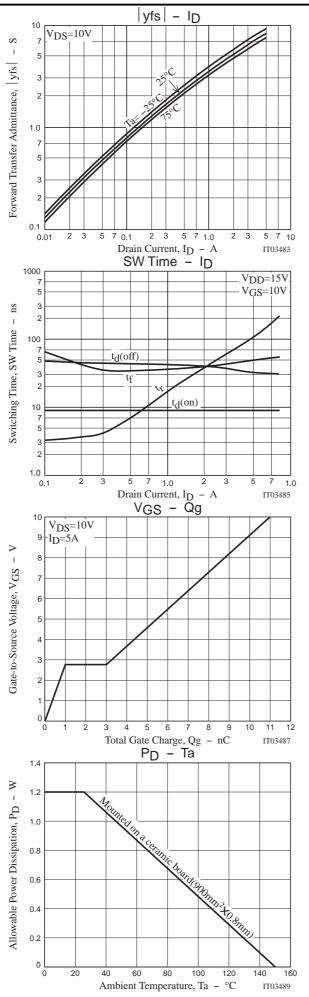
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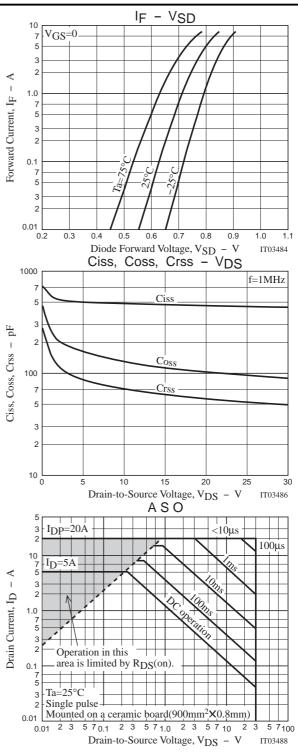
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Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		480		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		130		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		70		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit		9		ns
Rise Time	tr	See specified Test Circuit		64		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit		36		ns
Fall Time	tf	See specified Test Circuit		45		ns
Total Gate Charge	Qg	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =5A		11		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =5A		1.0		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =5A		2.0		nC
Diode Forward Voltage	V <sub>SD</sub>	IS=5A, VGS=0		0.8	1.2	V

### Switching Time Test Circuit







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